

TC7SET00F, TC7SET00FU

2-INPUT NAND GATE

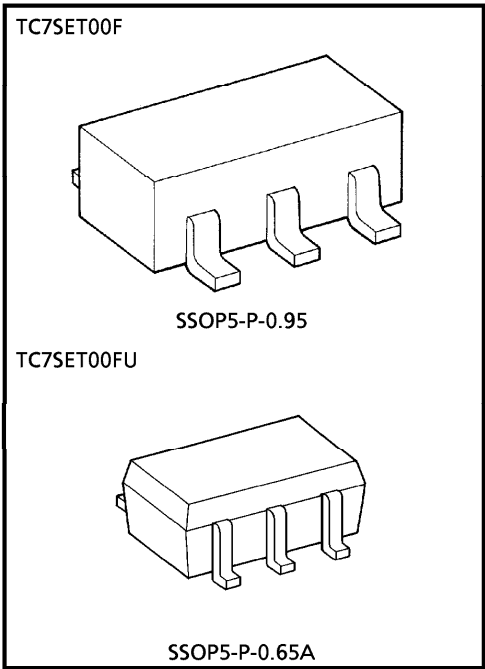
The TC7SET00 is an advanced high speed CMOS 2-INPUT NAND GATE fabricated with silicon gate CMOS technology. It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation. The input threshold levels are compatible with TTL output voltage. This device can be used for level converter for interfacing 3V to 5V system. An input protection circuit ensures that 0V to 7V can be applied to the input pins without regard to the supply voltage.

FEATURES

- High Speed $t_{pd} = 5.0ns$ (Typ.) at $V_{CC} = 5V$
- Low Power Dissipation $I_{CC} = 2\mu A$ (Max.) at $T_a = 25^{\circ}C$
- Compatible with TTL outputs $V_{IL} = 0.8V$ (Max.)
 $V_{IH} = 2.0V$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays $t_{pLH} \approx t_{pHL}$

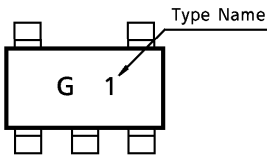
MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage Range	V_{CC}	- 0.5~7.0	V
DC Input Voltage	V_{IN}	- 0.5~7.0	V
DC Output Voltage	V_{OUT}	- 0.5~ $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	- 20	mA
Output Diode Current	I_{OK}	± 20	mA
DC Output Current	I_{OUT}	± 25	mA
DC V_{CC} / Ground Current	I_{CC}	± 50	mA
Power Dissipation	P_D	200	mW
Storage Temperature	T_{stg}	- 65~150	°C
Lead Temperature (10 s)	T_L	260	°C



Weight SSOP5-P-0.95 : 0.016g (Typ.)
SSOP5-P-0.65A : 0.006g (Typ.)

MARKING



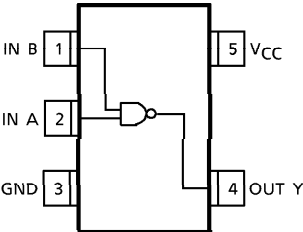
TRUTH TABLE

A	B	Y
L	L	H
L	H	H
H	L	H
H	H	L

LOGIC DIAGRAM



PIN ASSIGNMENT (TOP VIEW)



RECOMMENDED OPERATING CONDITIONS

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage	V_{CC}	4.5~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt/dv	0~20	ns/V

DC ELECTRICAL CHARACTERISTICS

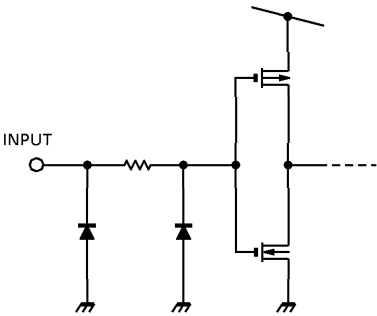
CHARACTERISTIC	SYMBOL	TEST CONDITION		V_{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT
					MIN.	TYP.	MAX.	MIN.	MAX.	
High-Level Input Voltage	V_{IH}			4.5~5.5	2.0	—	—	2.0	—	V
Low-Level Input Voltage	V_{IL}			4.5~5.5	—	—	0.8	—	0.8	V
High-Level Output Voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -50\mu A$	4.5	4.4	4.5	—	4.4	—	V
			$I_{OH} = -8mA$	4.5	3.94	—	—	3.80	—	
Low-Level Output Voltage	V_{OL}	$V_{IN} = V_{IH}$	$I_{OL} = 50\mu A$	4.5	—	0.0	0.10	—	0.10	V
			$I_{OL} = 8mA$	4.5	—	—	0.36	—	0.44	
Input Leakage Current	I_{IN}	$V_{IN} = 5.5V$ or GND		0~5.5	—	—	±0.1	—	±1.0	μA
Quiescent Supply Current	I_{CC}	$V_{IN} = V_{CC}$ or GND		5.5	—	—	2.0	—	20.0	μA
	I_{CCT}	PER INPUT : $V_{IN} = 3.4V$ OTHER INPUT : V_{CC} or GND		5.5	—	—	1.35	—	1.50	mA

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

CHARACTERISTIC	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = - 40~85°C		UNIT
		VCC (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time	tPLH	5.0 ± 0.5	15	—	4.7	6.2	1.0	7.1	ns
	tPHL		50	—	6.5	9.0	1.0	10.3	
Input Capacitance	CIN			—	4	10	—	10	pF
Power Dissipation Capacitance	CpD	(Note 1)		—	17	—	—	—	

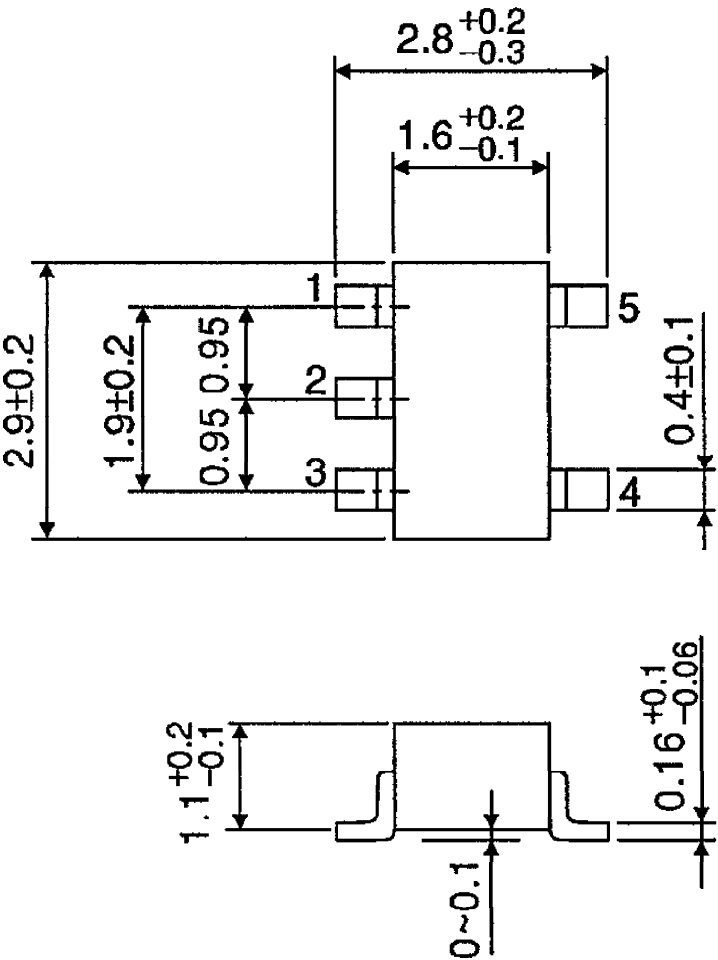
(Note 1) : CpD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.
Average operating current can be obtained by the equation :
 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

INPUT EQUIVALENT CIRCUIT



PACKAGE DIMENSIONS
SSOP5-P-0.95

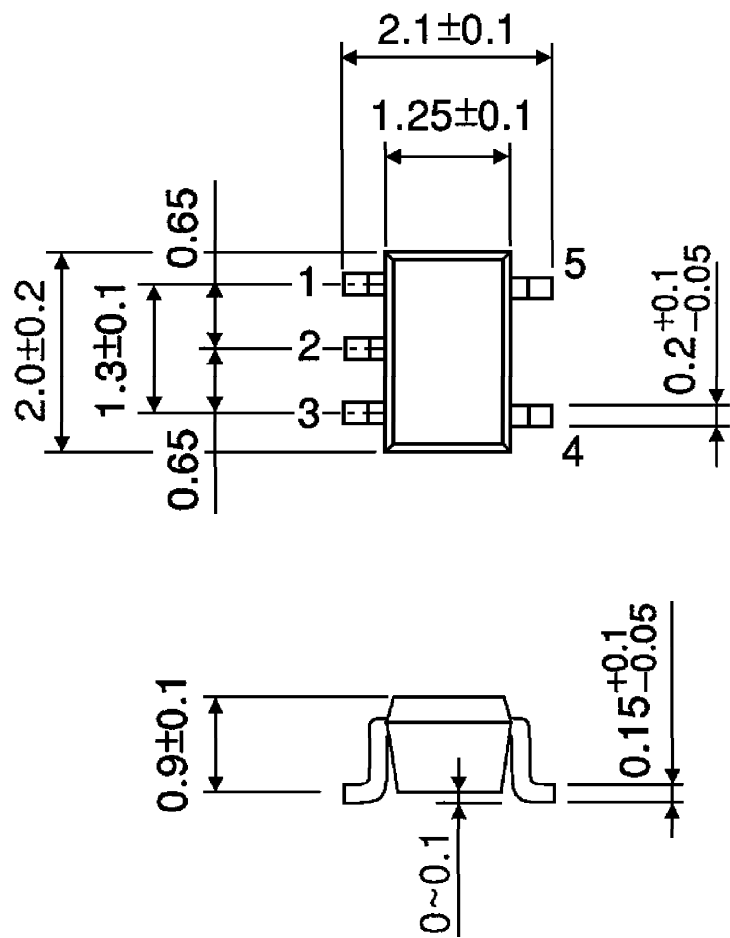
Unit : mm



Weight : 0.016g (Typ.)

PACKAGE DIMENSIONS
SSOP5-P-0.65A

Unit : mm



Weight : 0.006g (Typ.)

RESTRICTIONS ON PRODUCT USE

000707EBA

- TOSHIBA is continually working to improve the quality and reliability of its products. Nevertheless, semiconductor devices in general can malfunction or fail due to their inherent electrical sensitivity and vulnerability to physical stress. It is the responsibility of the buyer, when utilizing TOSHIBA products, to comply with the standards of safety in making a safe design for the entire system, and to avoid situations in which a malfunction or failure of such TOSHIBA products could cause loss of human life, bodily injury or damage to property. In developing your designs, please ensure that TOSHIBA products are used within specified operating ranges as set forth in the most recent TOSHIBA products specifications. Also, please keep in mind the precautions and conditions set forth in the "Handling Guide for Semiconductor Devices," or "TOSHIBA Semiconductor Reliability Handbook" etc..
- The TOSHIBA products listed in this document are intended for usage in general electronics applications (computer, personal equipment, office equipment, measuring equipment, industrial robotics, domestic appliances, etc.). These TOSHIBA products are neither intended nor warranted for usage in equipment that requires extraordinarily high quality and/or reliability or a malfunction or failure of which may cause loss of human life or bodily injury ("Unintended Usage"). Unintended Usage include atomic energy control instruments, airplane or spaceship instruments, transportation instruments, traffic signal instruments, combustion control instruments, medical instruments, all types of safety devices, etc.. Unintended Usage of TOSHIBA products listed in this document shall be made at the customer's own risk.
- The products described in this document are subject to the foreign exchange and foreign trade laws.
- The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by TOSHIBA CORPORATION for any infringements of intellectual property or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any intellectual property or other rights of TOSHIBA CORPORATION or others.
- The information contained herein is subject to change without notice.